

Experimental evidence for counter current flow in superconductor-superconductor bilayers

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ABSTRACT

We report evidence for counter current flow in superconductor-superconductor (SS) bilayers from depth-resolved measurements of their Meissner screening profiles using the low energy muon spin rotation (LE- μ SR) technique. In these experiments, the implantation depth of the muons can be tuned/adjusted/controlled between ~ 10 nm and ~ 150 nm below the surface, wherein their spin-precession reveals the field distribution inside the material (communicated via their radioactive decay products). Here we studied two prototypical SS bilayers [Nb-Ti-N(50nm)/Nb and Nb-Ti-N(80nm)/Nb] and compared the Meissner screening profiles obtained from LE- μ SR against Kubo's counter current flow model, as well a naive (bi)exponential model. From fits to Kubo's model, we obtain a magnetic penetration depth for the thin Nb-Ti-N layers of $\lambda_{\text{Nb-Ti-N}} = (201 \pm 4)$ nm, in good agreement with literature values. In contrast, a naive exponential model overestimates the $\lambda_{\text{Nb-Ti-N}}$ value by a factor of two, suggesting that it is inappropriate for quantifying $\lambda_{\text{Nb-Ti-N}}$ in the SS bilayer. This also indicates that the surface current is suppressed by the counter current flow in the bottom superconductor. Our result suggests that SS bilayers are a viable means of overcoming the theoretical field limit of Nb.

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